

Ultra-Low Capacitance ESD Protection Diodes

Micro-Packaged Diodes for ESD Protection

ESDL3552B

The ESDL3552B is designed to protect voltage sensitive components that require ultra-low capacitance from ESD and transient voltage events. Excellent clamping capability, low capacitance, high breakdown voltage, high linearity, low leakage, and fast response time make these parts ideal for ESD protection on designs where board space is at a premium. It has industry leading capacitance linearity over voltage making it ideal for high-speed data line protection applications.

Features

- Industry Leading Capacitance Linearity Over Voltage
- Ultra-Low Capacitance: 0.25 pF
- Insertion Loss: 0.26 dB @ 5 GHz
- 0201 Isolated DSN Package: 0.62 mm x 0.32 mm
- Stand-off Voltage: 5.0 V
- Low Leakage: < 50 nA
- Low Dynamic Resistance: < 1.0 Ω
- These Devices are Pb-Free, Halogen-Free/BFR-Free and are RoHS Compliant

Typical Applications

- High Speed Data Line Protection
- USB 2.0, USB 3.0, USB 3.1

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
IEC 61000-4-2 Level 4 (Contact) (Note 1) IEC 61000-4-2 Level 4 (Air) (Note 1)	ESD	± 20 ± 20	kV
Maximum Peak Pulse Current IEC 61000-4-5 8/20 μs (Lightning) (Note 2)	I_{PP}	2.0	A
Total Power Dissipation (Note 3) @ $T_A = 25^\circ\text{C}$ Thermal Resistance, Junction-to-Ambient	P_D $R_{\theta JA}$	300 400	mW $^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$
Lead Solder Temperature – Maximum (10 Second Duration)	T_L	260	$^\circ\text{C}$

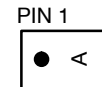
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Non-repetitive current pulse at $T_A = 25^\circ\text{C}$, per IEC61000-4-2 waveform.
2. Non-repetitive current pulse at $T_A = 25^\circ\text{C}$, per IEC61000-4-5 waveform.
3. Mounted with recommended minimum pad size, DC board FR-4

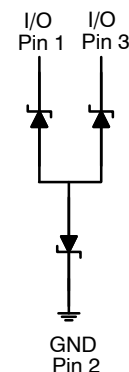


X4DFN3
CASE 718AB

MARKING DIAGRAM



A = Specific Device Code



ORDERING INFORMATION

Device	Package	Shipping [†]
ESDL3552BPFCT5G	X4DFN3 (Pb-Free/ Halide Free)	10000 / Tape & Reel

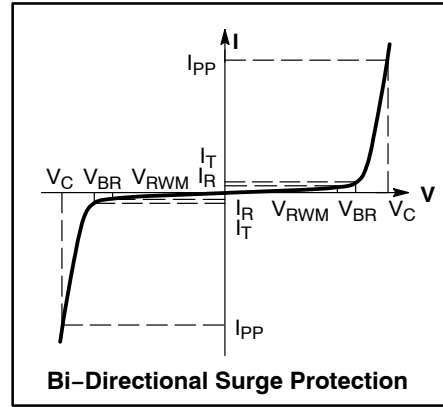
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current

*See Application Note [AND8308/D](#) for detailed explanations of datasheet parameters.



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}	Between any two pins (–40°C to +85°C)			5.0	V
Breakdown Voltage	V _{BR}	I _T = 10 mA, Between any two pins (–40°C to +85°C)	6.5	10.2	11.5	V
		I _T = 1 mA, Between any two pins	7.0	9.3	11	
Reverse Leakage Current	I _R	V _{RWM} = 5.0 V, T _A = 25°C		0.001	0.05	μA
		V _{RWM} = 5.0 V, T _A = 85°C		0.001	0.25	μA
Clamping Voltage TLP	V _C	I _{PP} = 4 A } IEC 61000–4–2 Level 1 equivalent (±2 kV Contact, ±4 kV Air) Pin 1 to Pin 2, Pin 3 to Pin 2		14.5		V
		I _{PP} = 16 A } IEC 61000–4–2 Level 4 equivalent (±8 kV Contact, ±16 kV Air) Pin 1 to Pin 2, Pin 3 to Pin 2		21.5		V
Reverse Peak Pulse Current	I _{PP}	IEC61000–4–5 (8x20 μs), Between any two pins	2.0	3.0		A
Clamping Voltage (8x20 μs)	V _C	I _{PP} = 2 A		14	18	V
Dynamic Resistance	R _{DYN}	100 ns TLP, Pin 1 to Pin 2, Pin 3 to Pin 2		0.58		Ω
Junction Capacitance	C _J	V _R = 0 V, f = 1 MHz, Between any two pins		0.25	0.30	pF
Capacitance Linearity	C _Δ	V _R = 0 V to 5 V, f = 1 MHz		0.03		pF
Insertion Loss	I _L	f = 2.5 GHz		0.16		dB
		f = 5.0 GHz		0.26		
		f = 10.0 GHz		0.41		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

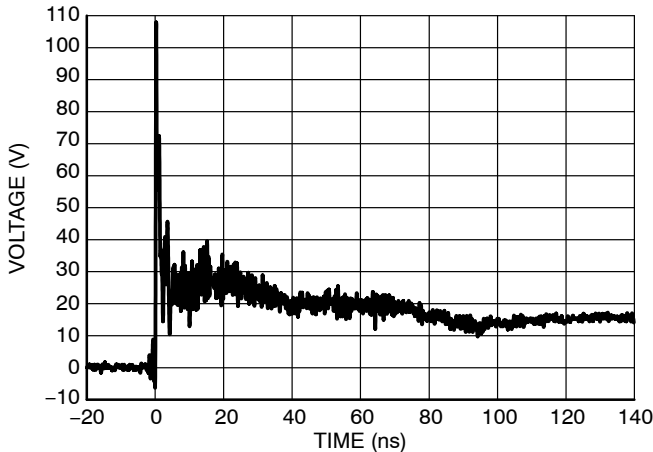


Figure 1. ESD Clamping Voltage Screenshot
Positive 8 kV Contact per IEC61000–4–2

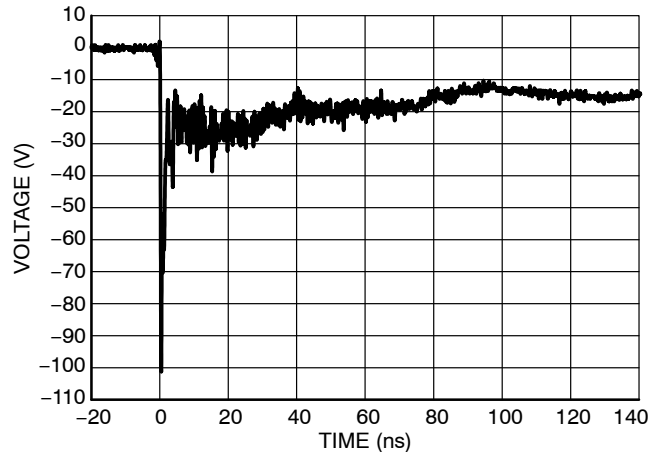


Figure 2. ESD Clamping Voltage Screenshot
Negative 8 kV Contact per IEC61000–4–2

TYPICAL CHARACTERISTICS

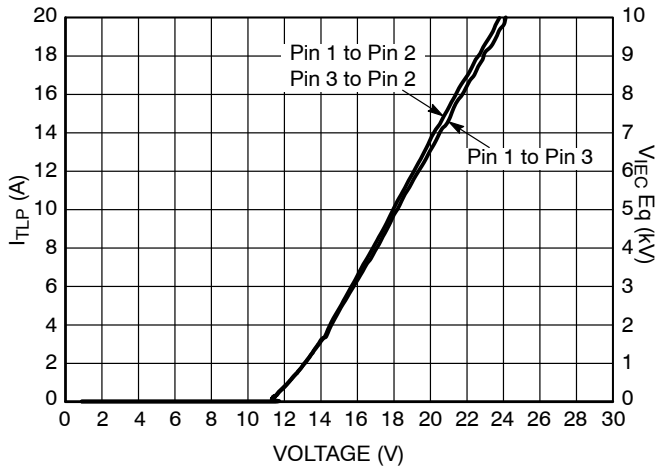


Figure 3. Positive TLP I-V Curve

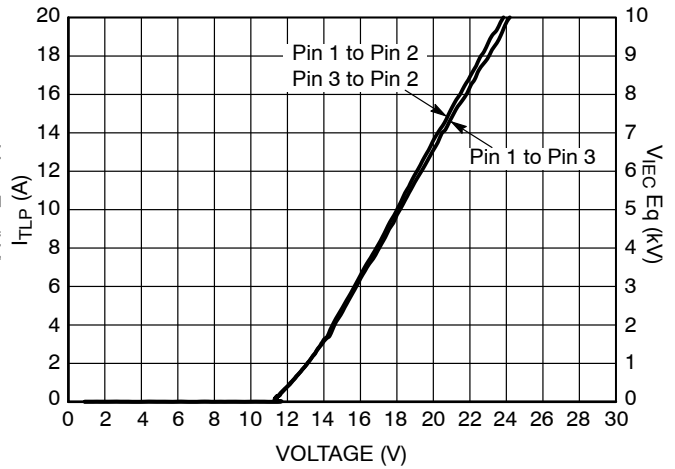


Figure 4. Negative TLP I-V Curve

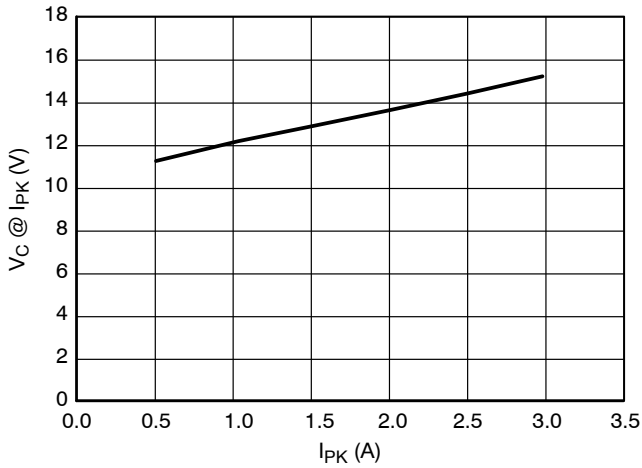


Figure 5. Positive Clamping Voltage vs. Peak Pulse Current ($t_p = 8/20 \mu s$)

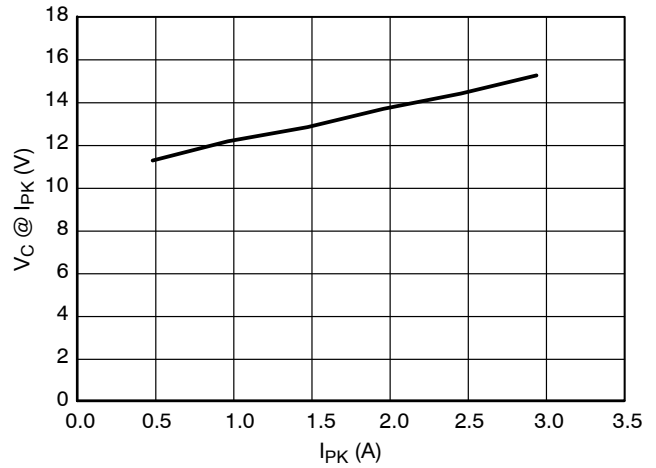


Figure 6. Negative Clamping Voltage vs. Peak Pulse Current ($t_p = 8/20 \mu s$)

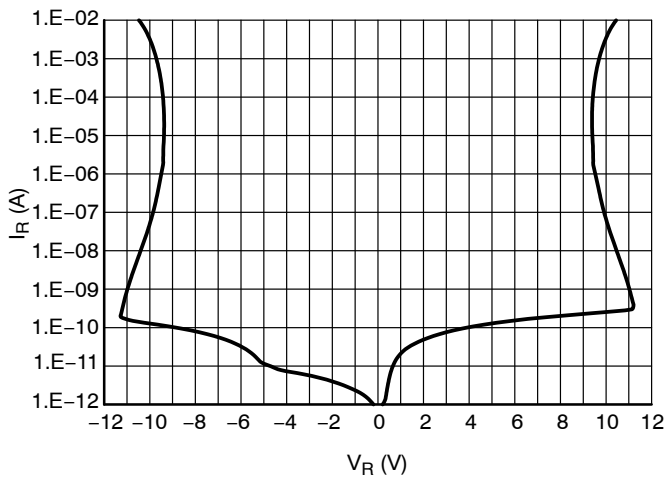


Figure 7. Breakdown Voltage

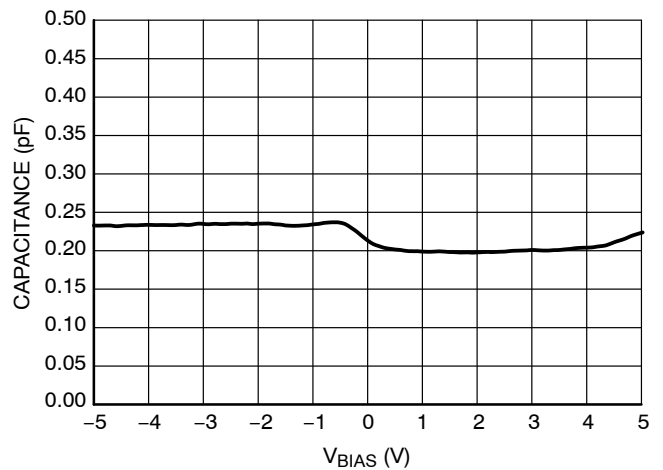


Figure 8. Line Capacitance, $f = 1 \text{ MHz}$

ESDL3552B

TYPICAL CHARACTERISTICS

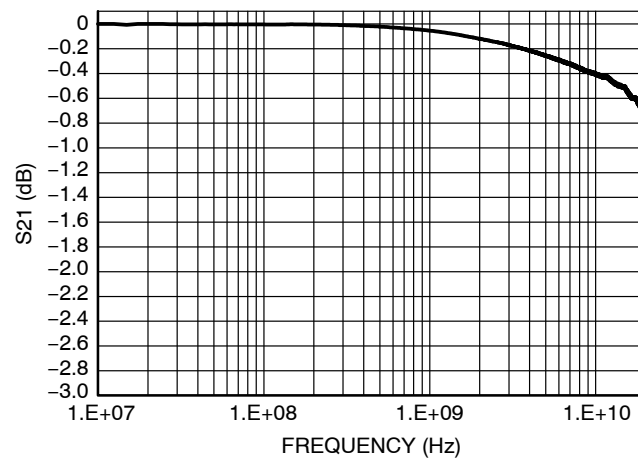


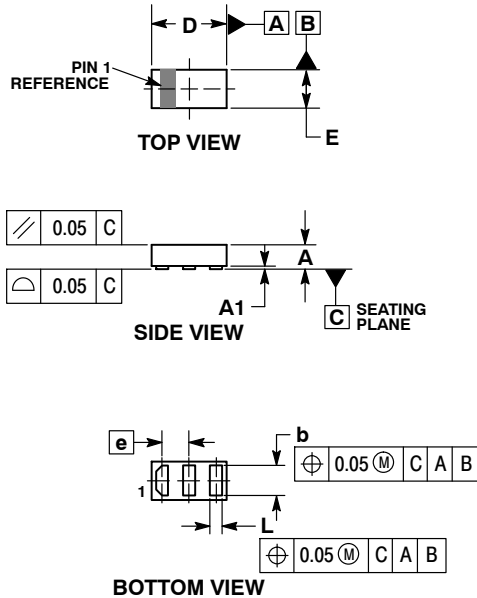
Figure 9. Insertion Loss



SCALE 8:1

X4DFN3 0.62x0.32, 0.225P
CASE 718AB
ISSUE A

DATE 13 MAR 2018

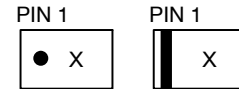


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.

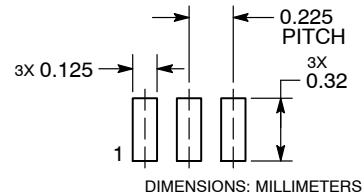
MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.175	0.20	0.225
A1	0.000	0.015	0.030
b	0.23	0.25	0.27
D	0.595	0.620	0.645
E	0.295	0.320	0.345
e	0.225 BSC		
L	0.08	0.10	0.12

GENERIC
MARKING DIAGRAMS*



X = Specific Device Code

RECOMMENDED
MOUNTING FOOTPRINT*



See Application Note AND8398/D for more mounting details

*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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